



3.3V CMOS 16-BIT REGISTERED TRANSCEIVER WITH 3-STATE OUTPUTS AND BUS-HOLD

IDT74ALVCH16543

FEATURES:

- 0.5 MICRON CMOS Technology
- Typical $t_{SK(0)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- 0.635mm pitch SSOP, 0.50mm pitch TSSOP, and 0.40mm pitch TVSOP packages
- Extended commercial range of -40°C to +85°C
- $V_{CC} = 3.3V \pm 0.3V$, Normal Range
- $V_{CC} = 2.7V$ to 3.6V, Extended Range
- $V_{CC} = 2.5V \pm 0.2V$
- CMOS power levels (0.4μW typ. static)
- Rail-to-Rail output swing for increased noise margin

Drive Features for ALVCH16543:

- High Output Drivers: ±24mA
- Suitable for heavy loads

APPLICATIONS:

- 3.3V High Speed Systems
- 3.3V and lower voltage computing systems

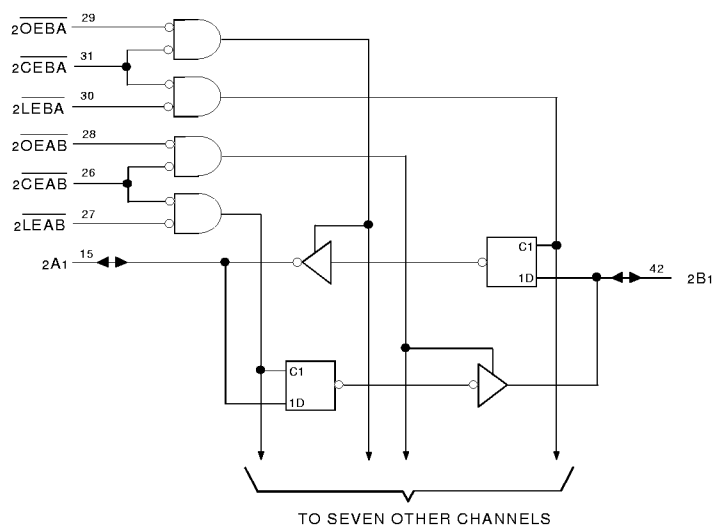
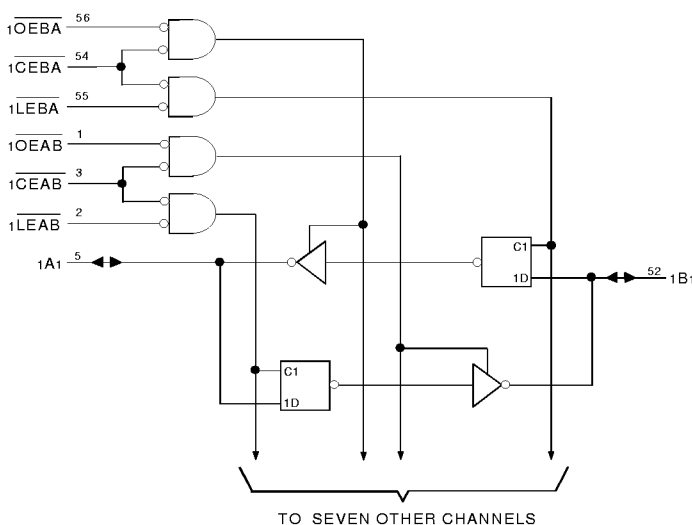
DESCRIPTION:

This 16-bit registered transceiver is built using advanced dual metal CMOS technology. The ALVCH16543 can be used as two 8-bit transceivers or one 16-bit transceiver. Separate latch-enable (\overline{LEAB} or \overline{LEBA}) and output-enable (\overline{OEAB} or \overline{OEBA}) inputs are provided for each register to permit independent control in either direction of data flow. The A-to-B enable (\overline{CEAB}) input must be low to enter data from A or to output data from B. If \overline{CEAB} is low and \overline{LEAB} is low, the A-to-B latches are transparent; a subsequent low-to-high transition of \overline{LEAB} puts the A latches in the storage mode. With \overline{CEAB} and \overline{OEAB} both low, the 3-state B outputs are active and reflect the data present at the output of the A latches. Data flow from B to A is similar, but requires using \overline{CEBA} , \overline{LEBA} , and \overline{OEBA} .

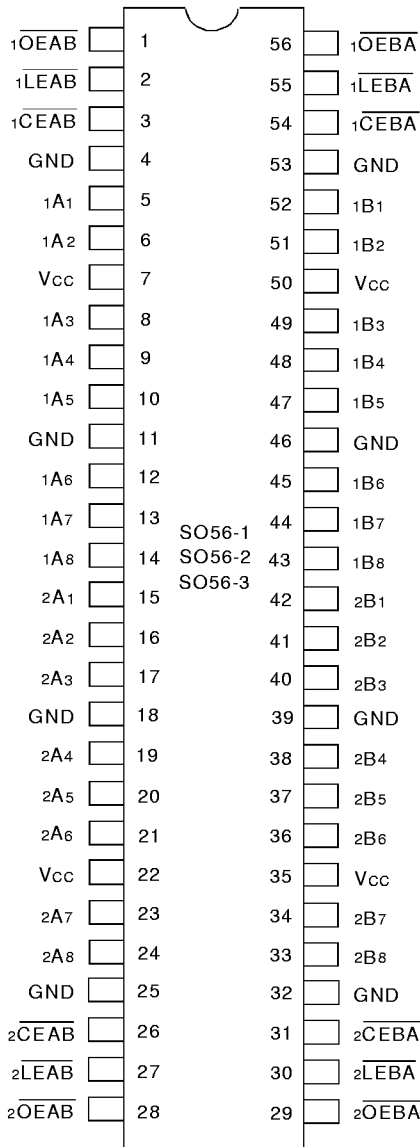
The ALVCH16543 has been designed with a ±24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

The ALVCH16543 has "bus-hold" which retains the inputs' last state whenever the input bus goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

Functional Block Diagram



PIN CONFIGURATION



SSOP/TSSOP/TVSOP
TOP VIEW

CAPACITANCE (T_A = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN}	Input Capacitance	V _{IN} = 0V	5	7	pF
C _{OUT}	Output Capacitance	V _{OUT} = 0V	7	9	pF
C _{I/O}	I/O Port Capacitance	V _{IN} = 0V	7	9	pF

NOTE:

- As applicable to the device type.

ABSOLUTE MAXIMUM RATING (1)

Symbol	Description	Max.	Unit
V _{TERM} ⁽²⁾	Terminal Voltage with Respect to GND	- 0.5 to + 4.6	V
V _{TERM} ⁽³⁾	Terminal Voltage with Respect to GND	- 0.5 to V _{CC} + 0.5	V
T _{STG}	Storage Temperature	- 65 to + 150	°C
I _{OUT}	DC Output Current	- 50 to + 50	mA
I _{IK}	Continuous Clamp Current, V _I < 0 or V _I > V _{CC}	± 50	mA
I _{OK}	Continuous Clamp Current, V _O < 0	- 50	mA
I _{CC} I _{SS}	Continuous Current through each V _{CC} or GND	±100	mA

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- V_{CC} terminals.
- All terminals except V_{CC}.

PIN DESCRIPTION

Pin Names	Description
x $\overline{\text{OEAB}}$	A-to-B Output Enable Inputs (Active LOW)
x $\overline{\text{OEBA}}$	B-to-A Output Enable Inputs (Active LOW)
x $\overline{\text{CEAB}}$	A-to-B Enable Inputs (Active LOW)
x $\overline{\text{CEBA}}$	B-to-A Enable Inputs (Active LOW)
x $\overline{\text{LEAB}}$	A-to-B Latch Enable Inputs (Active LOW)
x $\overline{\text{LEBA}}$	B-to-A Latch Enable Inputs (Active LOW)
xAx	A-to-B Data Inputs or B-to-A 3-State Outputs ⁽¹⁾
xBx	B-to-A Data Inputs or A-to-B 3-State Outputs ⁽¹⁾

NOTE:

- These pins have "Bus-Hold." All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (1, 2)

Inputs				Output
x $\overline{\text{CEAB}}$	x $\overline{\text{LEAB}}$	x $\overline{\text{OEAB}}$	xAx	xBx
H	X	X	X	Z
X	X	H	X	Z
L	H	L	X	B ₀
L	L	L	L	L
L	L	L	H	H

NOTES:

- A-to-B data flow is shown. B-to-A data flow is similar but uses x $\overline{\text{CEBA}}$, x $\overline{\text{LEBA}}$, and x $\overline{\text{OEBA}}$.
- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
Z = High-Impedance
B₀ = Level of B before the indicated steady-state inputs were established.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V _{IH}	Input HIGH Voltage Level	V _{CC} = 2.3V to 2.7V		1.7	—	—	V
		V _{CC} = 2.7V to 3.6V		2	—	—	
V _{IL}	Input LOW Voltage Level	V _{CC} = 2.3V to 2.7V		—	—	0.7	V
		V _{CC} = 2.7V to 3.6V		—	—	0.8	
I _{IH}	Input HIGH Current	V _{CC} = 3.6V	V _I = V _{CC}	—	—	± 5	μA
I _{IL}	Input LOW Current	V _{CC} = 3.6V	V _I = GND	—	—	± 5	
I _{OZH} I _{OZL}	High Impedance Output Current (3-State Output pins)	V _{CC} = 3.6V		—	—	± 10	μA
				V _O = V _{CC}	—	—	
V _{IK}	Clamp Diode Voltage	V _{CC} = 2.3V, I _{IN} = -18mA		—	-0.7	-1.2	V
V _H	Input Hysteresis	V _{CC} = 3.3V		—	100	—	mV
I _{CC1} I _{CC2} I _{CC3}	Quiescent Power Supply Current	V _{CC} = 3.6V V _{IN} = GND or V _{CC}		—	0.1	40	μA
ΔI _{CC}	Quiescent Power Supply Current Variation	One input at V _{CC} - 0.6V, other inputs at V _{CC} or GND		—	—	750	

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NOTE:

1. Typical values are at V_{CC} = 3.3V, +25°C ambient.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
I _{BHH} I _{BHL}	Bus-Hold Input Sustain Current	V _{CC} = 3.0V		-75	—	—	μA
				V _I = 2.0V	—	—	
I _{BHH} I _{BHL}	Bus-Hold Input Sustain Current	V _{CC} = 2.3V		75	—	—	μA
				V _I = 0.8V	—	—	
I _{BHHO} I _{BHLO}	Bus-Hold Input Overdrive Current	V _{CC} = 3.6V		-45	—	—	μA
				V _I = 1.7V	—	—	
I _{BHHO} I _{BHLO}	Bus-Hold Input Overdrive Current	V _{CC} = 3.6V		45	—	—	μA
				V _I = 0.7V	—	—	
I _{BHHO} I _{BHLO}	Bus-Hold Input Overdrive Current	V _{CC} = 3.6V		—	—	± 500	μA
				V _I = 0 to 3.6V	—	—	

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NOTES:

1. Pins with Bus-hold are identified in the pin description.
2. Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Max.	Unit
V _{OH}	Output HIGH Voltage	V _{CC} = 2.3V to 3.6V	I _{OH} = -0.1mA	V _{CC} - 0.2	—	V
		V _{CC} = 2.3V	I _{OH} = -6mA	2	—	
		V _{CC} = 2.3V	I _{OH} = -12mA	1.7	—	
		V _{CC} = 2.7V		2.2	—	
		V _{CC} = 3.0V		2.4	—	
		V _{CC} = 3.0V	I _{OH} = -24mA	2	—	
V _{OL}	Output LOW Voltage	V _{CC} = 2.3V to 3.6V	I _{OL} = 0.1mA	—	0.2	V
		V _{CC} = 2.3V	I _{OL} = 6mA	—	0.4	
			I _{OL} = 12mA	—	0.7	
		V _{CC} = 2.7V	I _{OL} = 12mA	—	0.4	
		V _{CC} = 3.0V	I _{OL} = 24mA	—	0.55	

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NOTE:

- V_{IH} and V_{IL} must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate V_{CC} range. T_A = -40°C to +85°C.

OPERATING CHARACTERISTICS, T_A = 25°C

Symbol	Parameter	Test Conditions	V _{CC} = 2.5V ± 0.2V	V _{CC} = 3.3V ± 0.3V	Unit
			Typical	Typical	
CPD	Power Dissipation Capacitance Outputs enabled	C _L = 0pF, f = 10MHz	54	64	pF
CPD	Power Dissipation Capacitance Outputs disabled		6	7	pF

SWITCHING CHARACTERISTICS ⁽¹⁾

Symbol	Parameter	V _{CC} = 2.5V ± 0.2V		V _{CC} = 2.7V		V _{CC} = 3.3V ± 0.3V		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{PLH} t _{PHL}	Propagation Delay xAx to xBx or xBx to xAx	1	5.1	—	4.8	1	4.3	ns
t _{PLH} t _{PHL}	Propagation Delay xLEAB to xBx or xLEBA to xAx	1	6.5	—	6.2	1.1	5	ns
t _{PZH} t _{PZL}	Output Enable Time xCEAB to xBx or xCEBA to xAx	1	7.2	—	6.9	1	5.6	ns
t _{PHZ} t _{PLZ}	Output Disable Time xCEAB, to xBx or xCEBA to xAx	1.3	6.1	—	6.2	1.5	5.1	ns
t _{PZH} t _{PZL}	Output Enable Time xOEAB to xBx or xOEBA to xAx	1	6.8	—	6.3	1	5.3	ns
t _{PHZ} t _{PLZ}	Output Disable Time xOEAB to xBx or xOEBA to xAx	1	5.7	—	4.8	1.1	4.6	ns
tsu	Setup Time, data before $\overline{CE}\uparrow$	1.2	—	1.5	—	1.2	—	ns
tsu	Setup Time, data before $\overline{LE}\uparrow, \overline{CE}$ LOW	1.2	—	1.5	—	1.2	—	ns
th	Hold Time, data after $\overline{CE}\uparrow$	1.2	—	0.8	—	1.3	—	ns
th	Hold Time, data after $\overline{LE}\uparrow, \overline{CE}$ LOW	1.2	—	0.8	—	1.3	—	ns
tw	Pulse Duration, \overline{LE} or \overline{CE} LOW	3.3	—	3.3	—	3.3	—	ns
tsk(o)	Output Skew ⁽²⁾	—	—	—	—	—	500	ps

NOTES:

1. See test circuits and waveforms. T_A = -40°C to +85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

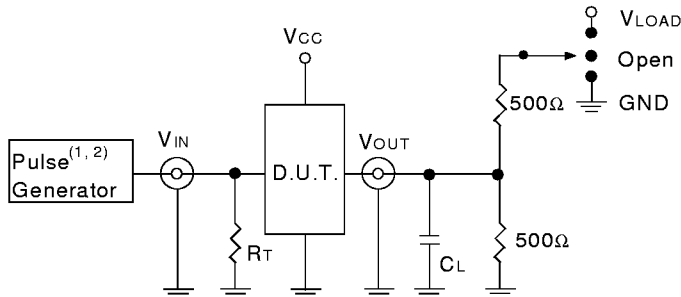
TEST CIRCUITS AND WAVEFORMS:

TEST CONDITIONS

Symbol	V _{cc} (1)= 3.3V±0.3V	V _{cc} (1)= 2.7V	V _{cc} (2)= 2.5V±0.2V	Unit
V _{LOAD}	6	6	2 x V _{cc}	V
V _{IH}	2.7	2.7	V _{cc}	V
V _T	1.5	1.5	V _{cc} / 2	V
V _{LZ}	300	300	150	mV
V _{HZ}	300	300	150	mV
C _L	50	50	30	pF

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TEST CIRCUITS FOR ALL OUTPUTS



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DEFINITIONS:

C_L = Load capacitance: includes jig and probe capacitance.

R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

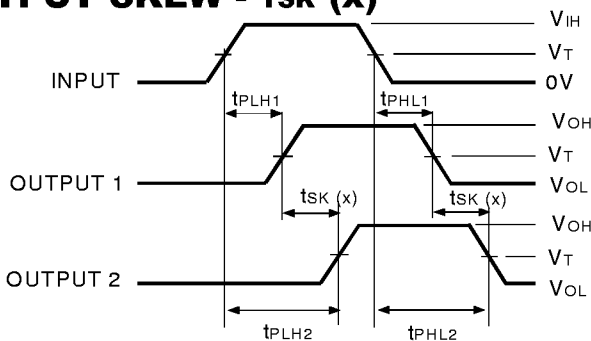
1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2.5ns; t_R ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_F ≤ 2ns; t_R ≤ 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	V _{LOAD}
Disable High Enable High	GND
All Other tests	Open

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OUTPUT SKEW - t_{SK} (x)



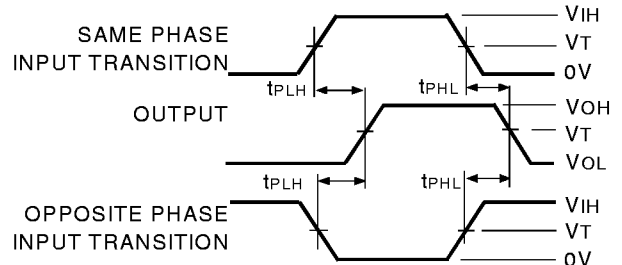
$$t_{SK}(x) = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

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NOTES:

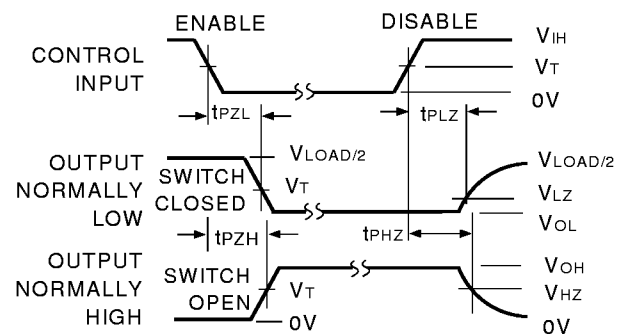
1. For t_{SK}(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t_{SK}(b) OUTPUT1 and OUTPUT2 are in the same bank.

PROPAGATION DELAY



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ENABLE AND DISABLE TIMES

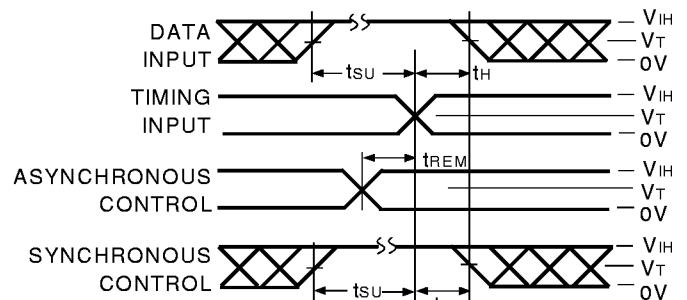


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NOTE:

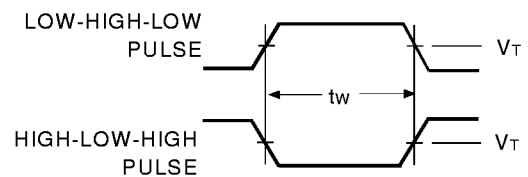
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

SET-UP, HOLD, AND RELEASE TIMES



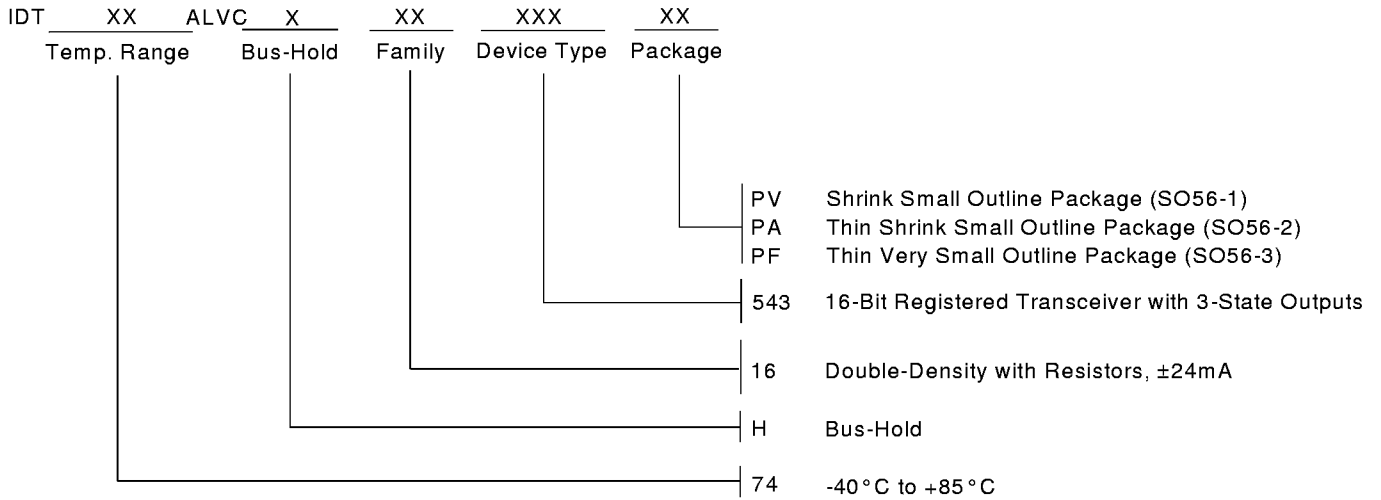
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PULSE WIDTH



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ORDERING INFORMATION



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